

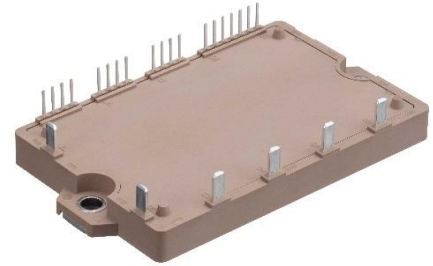
7MBP35XJN120-50

IGBT Modules

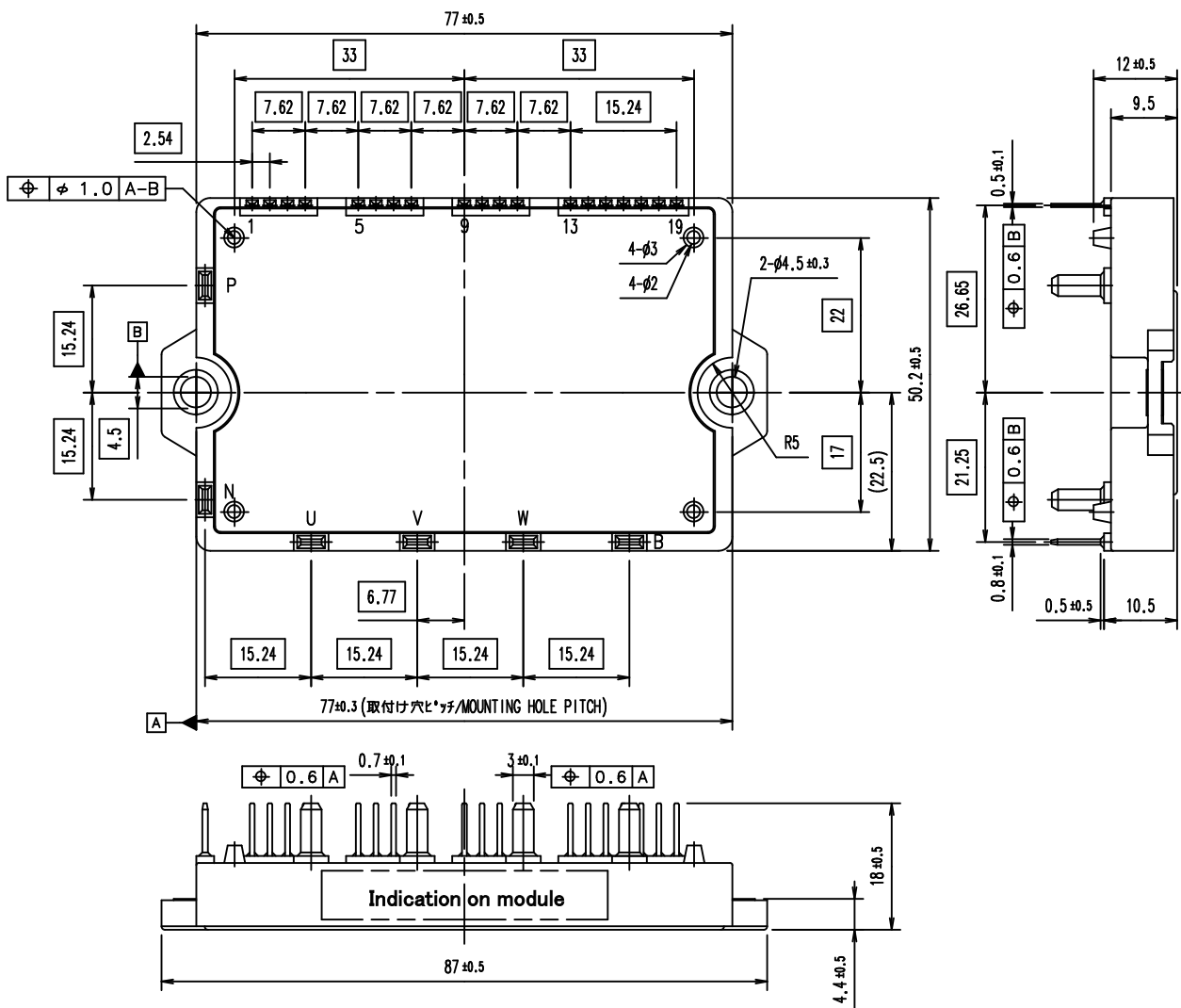
IGBT Module (X series)
1200V / 35A / IPM

■ **Features**

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



■ **Outline drawing (Unit : mm)**



Weight: 100g(typ.)

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IGBT Modules
■ Absolute maximum ratings
 $T_C=25^{\circ}\text{C}$, $T_{vj}=25^{\circ}\text{C}$, $V_{CC}=15\text{V}$ unless otherwise specified

Items		Symbol	Conditions	Min.	Max.	Units
Collector-Emitter voltage		V_{CES}	*1	-	1200	V
Short circuit voltage		V_{SC}	*2	400	800	V
Inverter	Collector current	I_C	DC	-	35	A
		I_{CP}	1ms	-	70	A
		$-I_C$	Duty=100% *3	-	35	A
	Total power dissipation	P_{tot}	IGBT 1 device *4	-	357	W
Brake	Repetitive peak reverse voltage	V_{RRM}	Diode part	-	1200	V
	Collector current	I_C	DC	-	25	A
		I_{CP}	1ms	-	50	A
	Forward current of diode	I_F		-	25	A
Total power dissipation	P_{tot}	IGBT 1 device *4	-	258	W	
Supply voltage of pre-driver		V_{CC}	*5	-0.5	20	V
Input signal voltage		V_{in}	*6	-0.5	$V_{CC}+0.5$	V
Alarm signal voltage		V_{ALM}	*7	-0.5	V_{CC}	V
Alarm signal current		I_{ALM}	*8	-	20	mA
Virtual junction temperature		T_{vj}		-	175	$^{\circ}\text{C}$
Operating virtual junction temperature		T_{vjop}		-	150	$^{\circ}\text{C}$
Operating case temperature		T_c		-20	125	$^{\circ}\text{C}$
Storage temperature		T_{stg}		-40	125	$^{\circ}\text{C}$
Solder temperature		T_{sol}	*9	-	260	$^{\circ}\text{C}$
Isolating voltage		V_{isol}	*10	-	2500	Vrms
Mounting torque of screws to heat sink		M_s	Mounting(M4)	-	1.7	Nm
Mounting torque of screws to terminals		M_t	Main terminals(M4)	-	-	Nm

Notes

- *1: V_{CES} shall be applied to the input voltage between terminal P-(U,V, W) and (U,V, W,B)-N.
- *2: In the case of the load inductance to be over $1\mu\text{H}$.
- *3: Duty= $150^{\circ}\text{C}/R_{th(j-c)D}/(I_F \times V_F \text{ Max.}) \times 100$
- *4: $P_{tot}=150^{\circ}\text{C}/R_{th(j-c)Q}$
- *5: V_{CC} shall be applied to the input voltage between terminal No.4 and 1, 8 and 5, 12 and 9,14 and 13.
- *6: V_{in} shall be applied to the input voltage between terminal No.3 and 1, 7 and 5, 11 and 9,15~18 and 13.
- *7: V_{ALM} shall be applied to the voltage between terminal No.2 and 1, 6 and 5, 10 and 9, 19 and 13.
- *8: I_{ALM} shall be applied to the input current to terminal No.2,6,10 and 19.
- *9: Immersion time 10 ± 1 sec. 1 time.
- *10: Terminal to base, 50/60Hz sine wave 1 min. All terminals should be connected together during the test.

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IGBT Modules

Electrical characteristics

Main circuit

$T_{vj}=25^{\circ}\text{C}$, $V_{CC}=15\text{V}$ unless otherwise specified

Item		Symbol	Conditions	Min.	Typ.	Max.	Units	
Inverter	Collector current at off signal input	I_{CES}	$V_{CE} = 1200\text{V}$	-	-	1.0	mA	
	Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_C = 35\text{A}$	Terminal	-	-	1.80	V
				Chip	-	1.40	-	V
	Forward voltage of FWD	V_F	$I_F = 35\text{A}$	Terminal	-	-	2.45	V
Chip				-	2.00	-	V	
Brake	Collector current at off signal input	I_{CES}	$V_{CE} = 1200\text{V}$	-	-	1.0	mA	
	Reverse current	I_{RRM}	$V_R = 1200\text{V}$	-	-	1.0	mA	
	Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_C = 25\text{A}$	Terminal	-	-	1.9	V
				Chip	-	1.45	-	V
Forward voltage of FWD	V_F	$I_F = 25\text{A}$	Terminal	-	-	2.7	V	
			Chip	-	2.30	-	V	
Switching time *11	t_{on}	$I_C = 35\text{A}$	$T_{vj}=150^{\circ}\text{C}$	$V_{DC} = 600\text{V}$	0.5	-	-	μs
	$t_{d(on)}$				0.5	-	-	μs
	t_{off}	-	-	2.0	μs			
	$t_{d(off)}$	-	-	1.7	μs			
	t_{rr}	$I_F = 35\text{A}$	$T_{vj}=150^{\circ}\text{C}$	$V_{DC} = 600\text{V}$	-	-	0.5	μs

*11: Turn on time (t_{on}) = $t_{d(on)} + t_r$, Turn off time (t_{off}) = $t_{d(off)} + t_f$

Control circuit

$T_{vj}=25^{\circ}\text{C}$, $V_{CC}=15\text{V}$ unless otherwise specified

Item	Symbol	Conditions	Min.	Typ.	Max.	Units	
Supply current of P-side pre-driver (per one unit)	I_{ccp}	Switching frequency (f_{sw}) = 0~15kHz $T_C = -20\sim 125^{\circ}\text{C}$	-	-	10	mA	
Supply current of N-side pre-driver	I_{ccn}		-	-	36	mA	
Input signal threshold voltage	$V_{inth(on)}$	$V_{in}\text{-GND}$	ON	1.2	1.4	1.6	V
	$V_{inth(off)}$		OFF	1.5	1.7	1.9	V

Protection circuit

$T_{vj}=25^{\circ}\text{C}$, $V_{CC}=15\text{V}$ unless otherwise specified

Item	Symbol	Conditions	Min.	Typ.	Max.	Units	
Over current protection level	I_{OC}	$T_{vj}=150^{\circ}\text{C}$ Resistance load	53	-	-	A	
			38	-	-	A	
Over current protection delay time	t_{dOC}	$T_{vj}=150^{\circ}\text{C}$	-	4.0	-	μs	
Short circuit protection delay time	t_{dSC}	$T_{vj}=150^{\circ}\text{C}$	-	1.0	-	μs	
IGBT chips over heating protection temperature level	T_{jOH}	Surface of IGBT chips	175	-	-	$^{\circ}\text{C}$	
Over heating protection hysteresis	T_{jH}		-	20	-	$^{\circ}\text{C}$	
Under voltage protection level	V_{UV}		11.0	-	12.5	V	
Under voltage protection hysteresis	V_H		0.2	0.5	-	V	
Alarm signal hold time	$t_{ALM(OC)}$	ALM-GND	1.0	2.0	2.4	ms	
	$t_{ALM(UV)}$	$T_C = -20\sim 125^{\circ}\text{C}$	$V_{CC} \geq 10\text{V}$	3.5	4.0	4.5	ms
	$t_{ALM(TjOH)}$			7.0	8.0	9.0	ms
Alarm signal voltage	V_{ALMH}	ALM-GND, without protection	14.5	-	15.0	V	
Resistance for current limit	R_{ALM}		960	-	1570	Ω	

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■ Thermal resistance characteristics ($T_c = 25^\circ\text{C}$)

Item			Symbol	Min.	Typ.	Max.	Units
Thermal resistance junction to case *12	Inverter	IGBT	$R_{th(j-c)Q}$	-	-	0.42	K/W
		FWD	$R_{th(j-c)D}$	-	-	0.64	K/W
	Brake	IGBT	$R_{th(j-c)Q}$	-	-	0.58	K/W
		FWD	$R_{th(j-c)D}$	-	-	1.23	K/W
Thermal resistance case to heat sink *13			$R_{th(c-s)}$	-	0.05	-	K/W

*12: For 1 device, the measurement point of the case is just under the chip.

*13: This is the value which is defined mounting on the additional heat sink with 1 W/(m·K) thermal grease.

■ Noise immunity ($V_{DC}=600\text{V}$, $V_{CC}=15\text{V}$)

Item	Conditions	Min.	Typ.	Max.	Units
Common mode rectangular noise	Pulse width 1 μs , polarity \pm , 10min. Judge: no over-current, no miss operating	± 2.0	-	-	kV

■ Recommended operating conditions

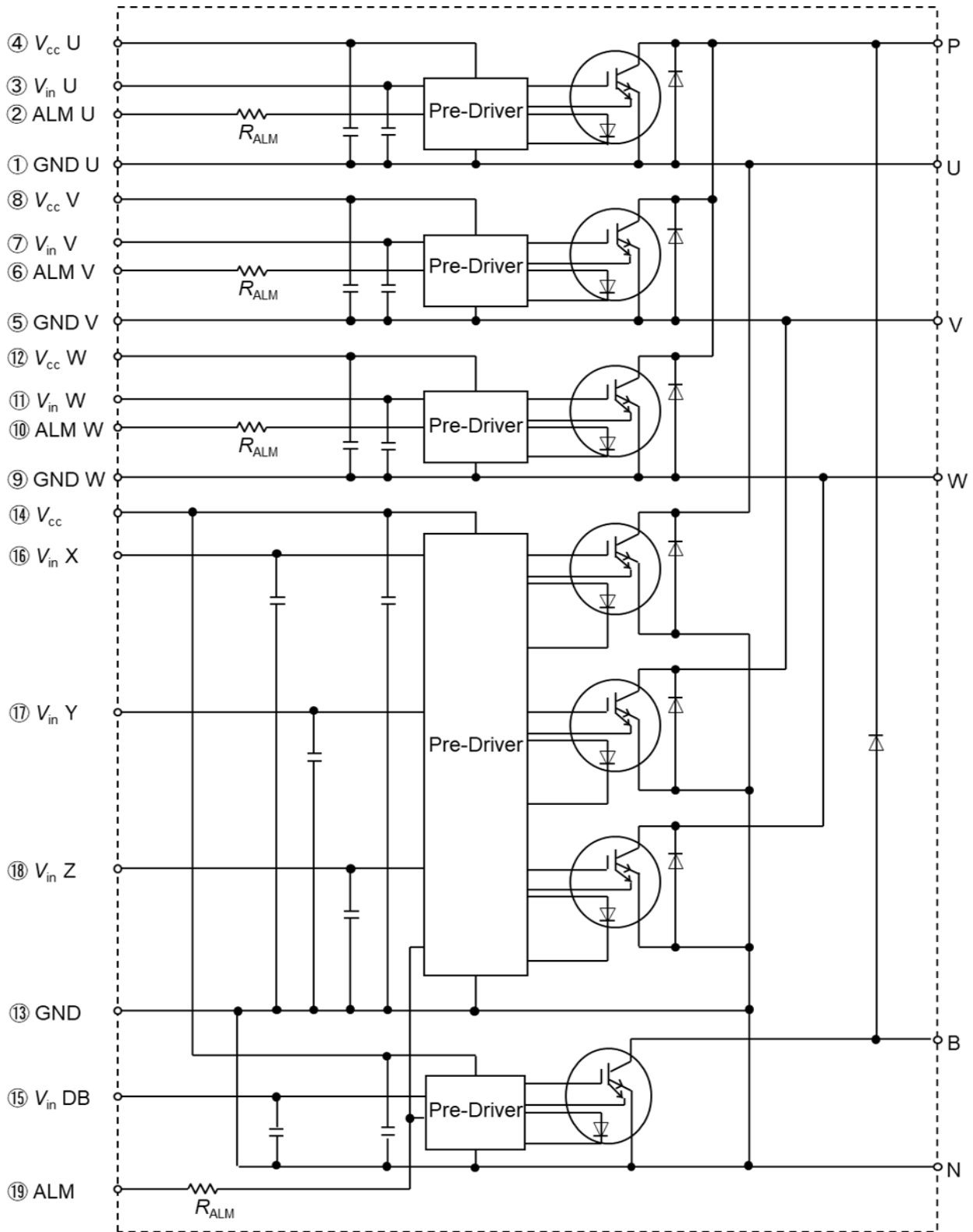
Item	Symbol	Min.	Typ.	Max.	Units
DC bus voltage	V_{DC}	-	-	800	V
Power supply voltage of pre-driver	V_{CC}	13.5	15.0	16.5	V
Switching frequency of IPM	f_{sw}	-	-	20.0	kHz
Arm short through blocking time for IPM's input signal *14	t_{dead}	1.5	-	-	μs
Screw torque (M4)	-	1.3	-	1.7	Nm

*14: $t_{dead} = t_{off} - t_{d(on)}$

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IGBT Modules

■ Block diagram



Pre-drivers include following functions

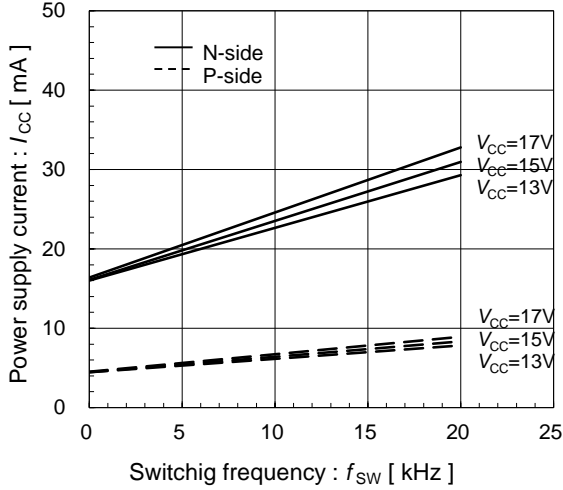
1. Amplifier for driver
2. Short circuit protection
3. Under voltage lockout circuit
4. Over current protection
5. IGBT chip over heating protection

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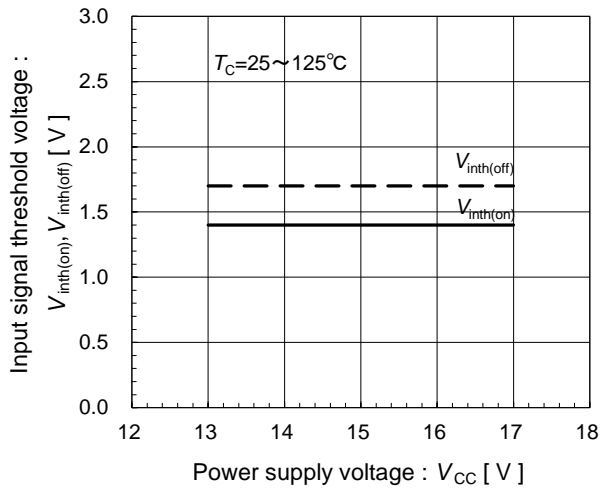
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■ Characteristics (representative)
● Control circuit

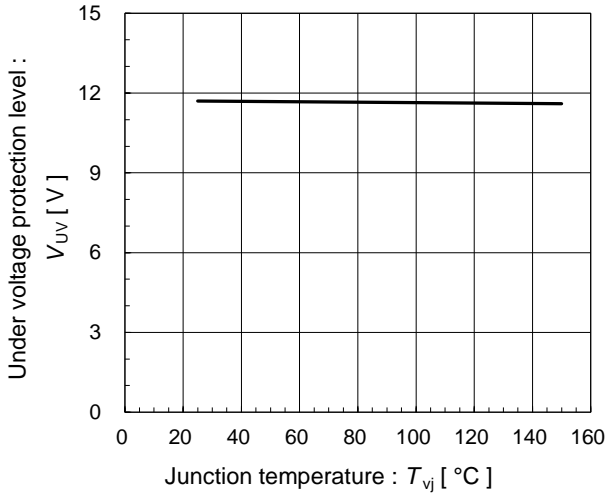
Power supply current vs. Switching frequency (typ.)
 $T_{vj} = 25^\circ\text{C}$



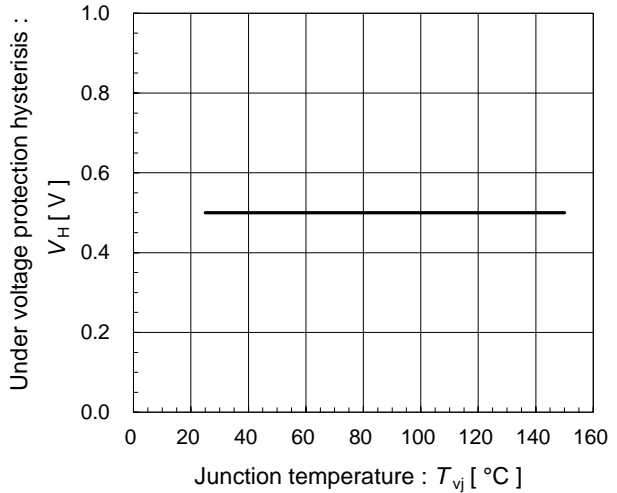
Input signal threshold voltage vs. Power supply voltage (typ.)
 $T_c = 25 \sim 125^\circ\text{C}$



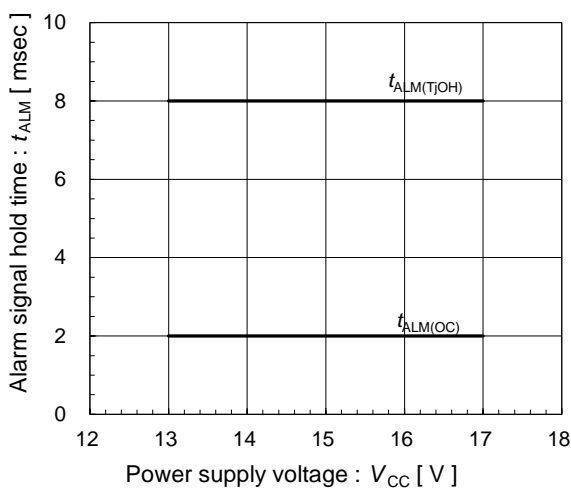
Under voltage protection level vs. Junction temperature (typ.)



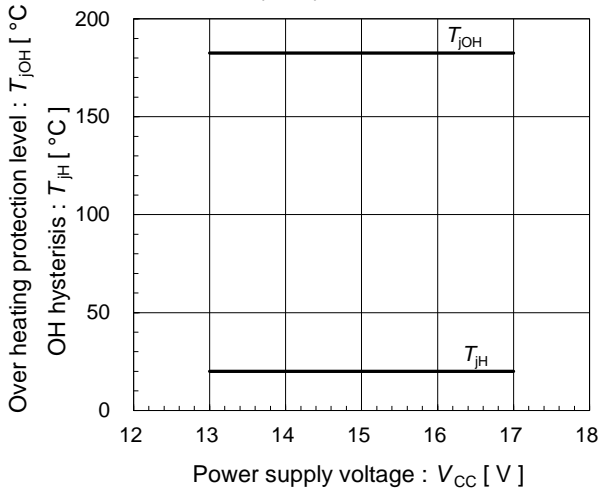
Under voltage protection hysteresis vs. Junction temperature (typ.)



Alarm signal hold time vs. Power supply voltage (typ.)



Over heating characteristics
 T_{jOH}, T_{jH} vs. V_{CC} (typ.)

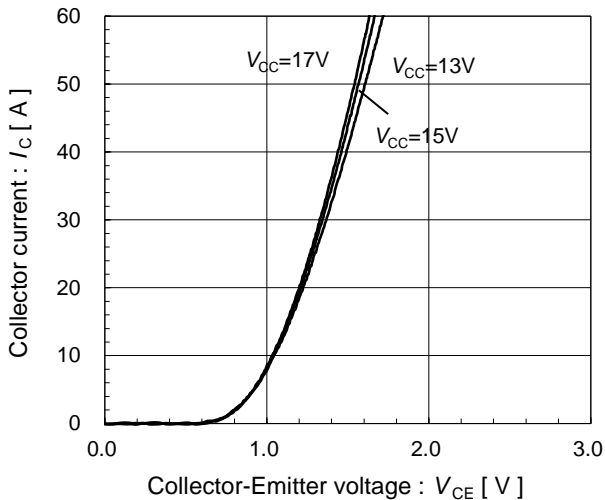


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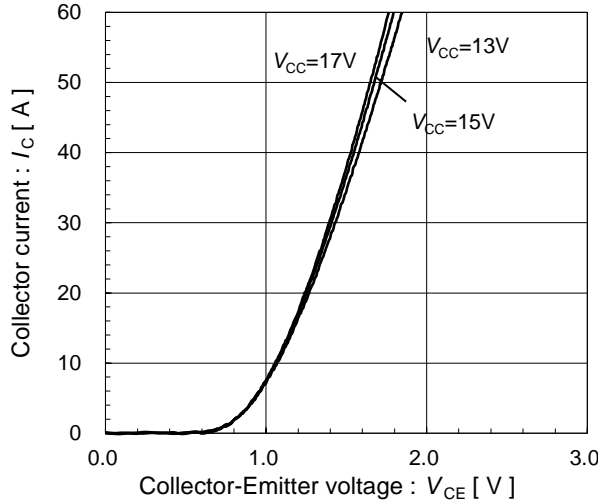
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● Inverter

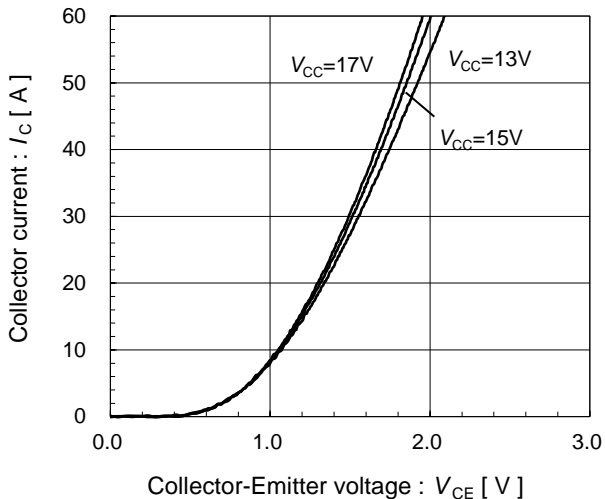
Collector current vs. Collector-Emmitter voltage (typ.)
 $T_{vj}=25^{\circ}\text{C}$ [Chip]



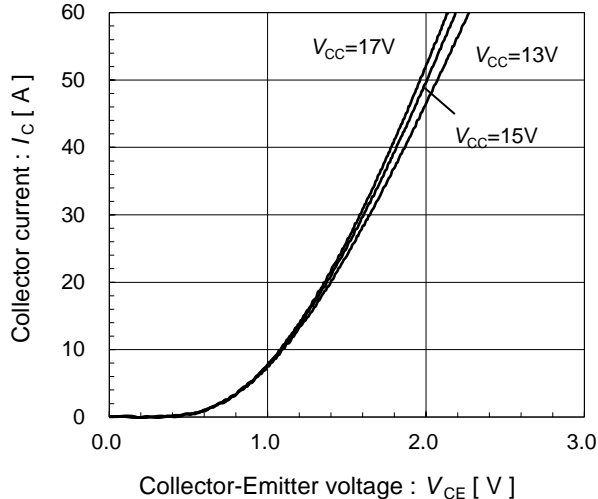
Collector current vs. Collector-Emmitter voltage (typ.)
 $T_{vj}=25^{\circ}\text{C}$ [Terminal]



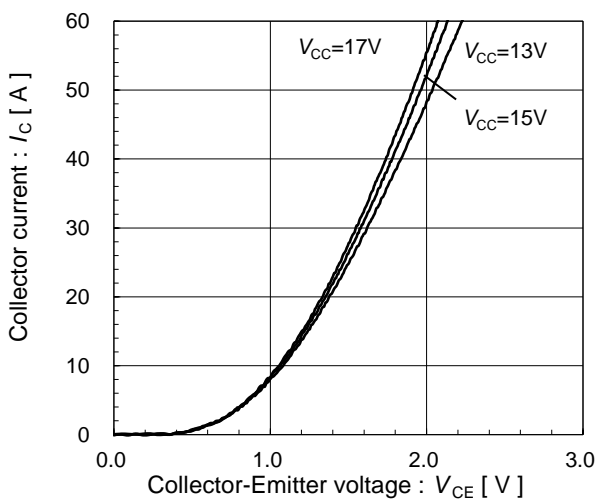
Collector current vs. Collector-Emmitter voltage (typ.)
 $T_{vj}=125^{\circ}\text{C}$ [Chip]



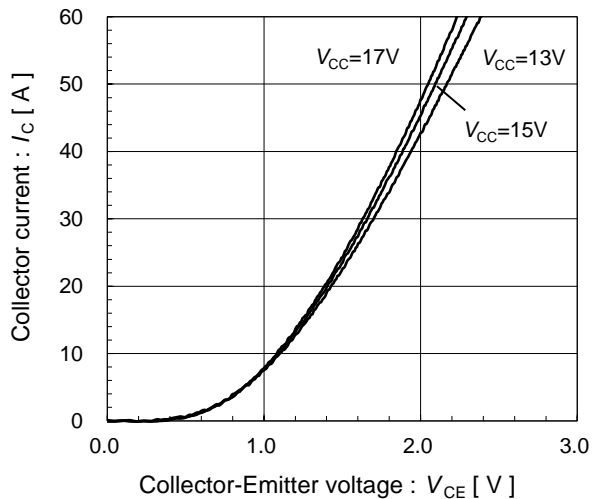
Collector current vs. Collector-Emmitter voltage (typ.)
 $T_{vj}=125^{\circ}\text{C}$ [Terminal]



Collector current vs. Collector-Emmitter voltage (typ.)
 $T_{vj}=150^{\circ}\text{C}$ [Chip]

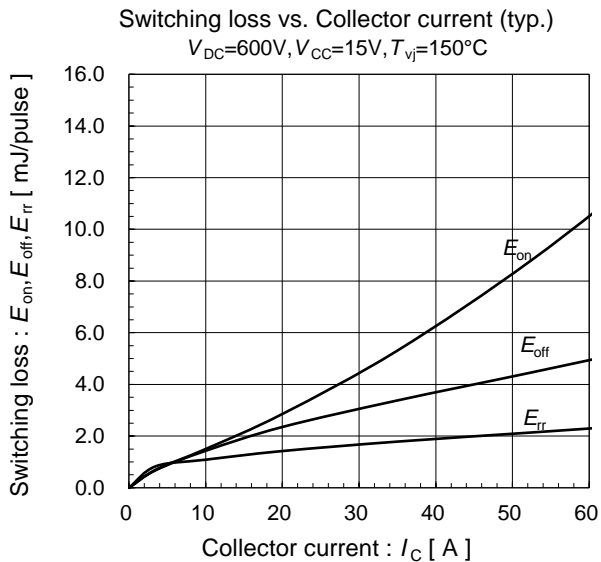
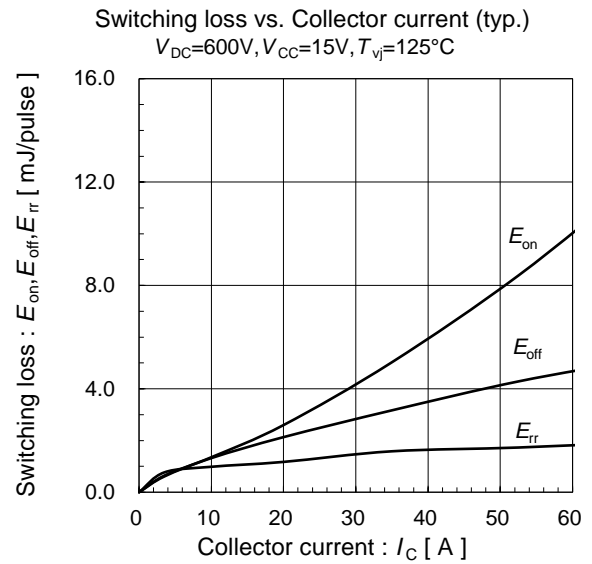
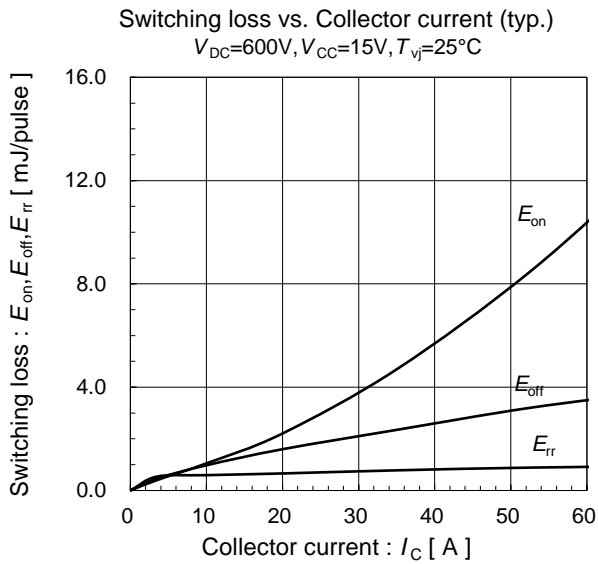
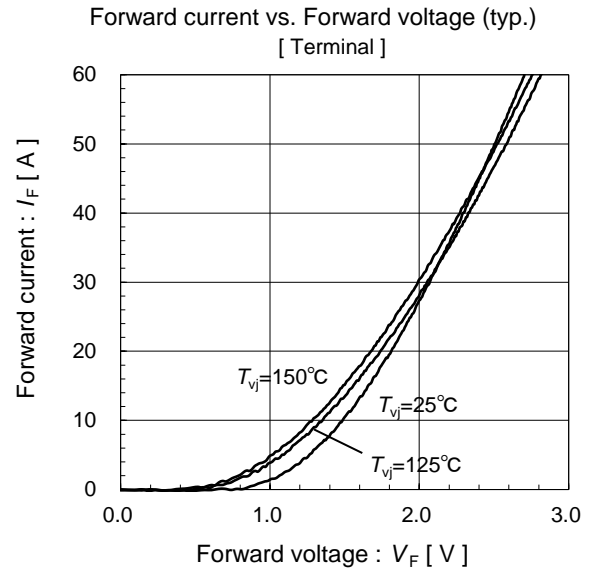
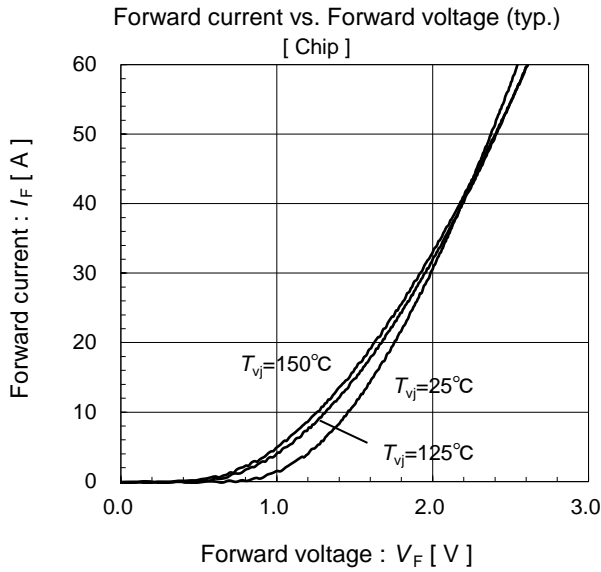


Collector current vs. Collector-Emmitter voltage (typ.)
 $T_{vj}=150^{\circ}\text{C}$ [Terminal]



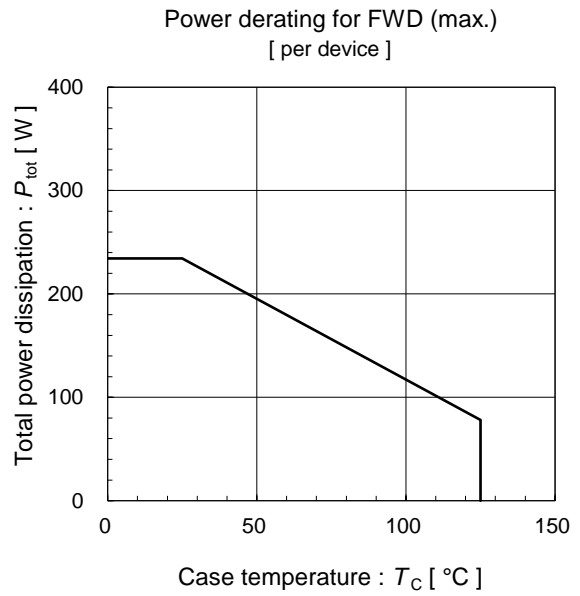
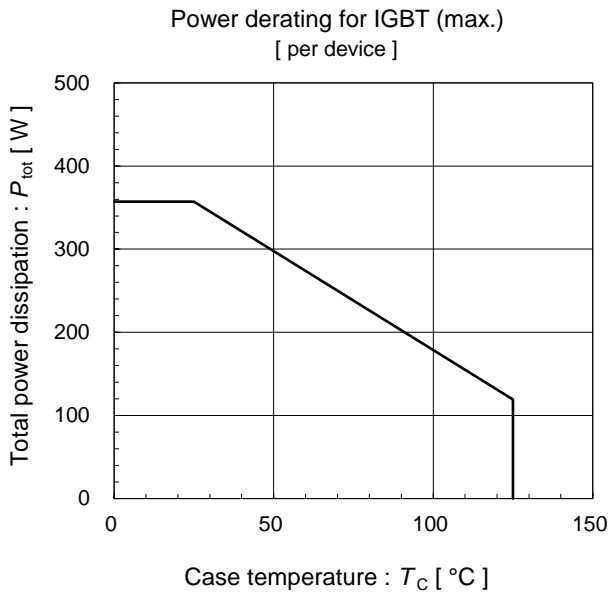
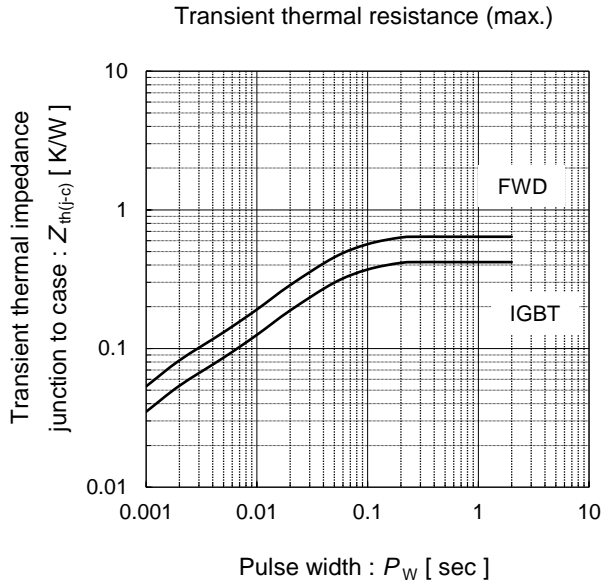
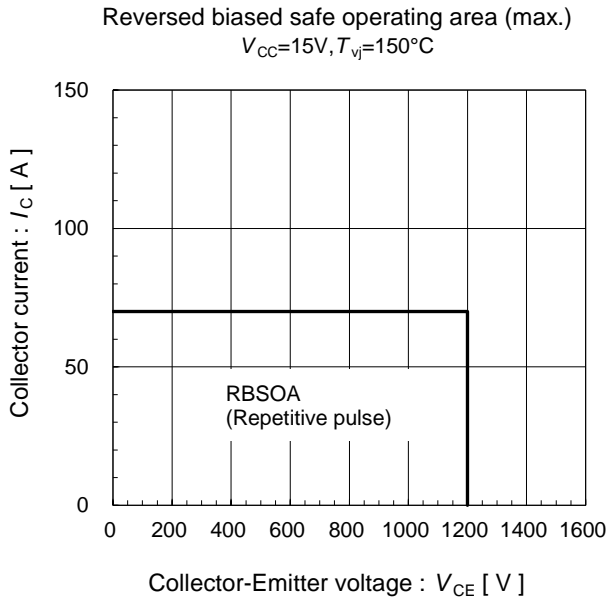
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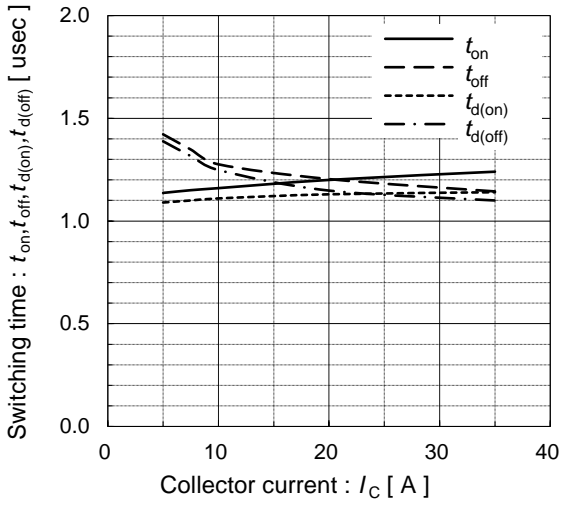


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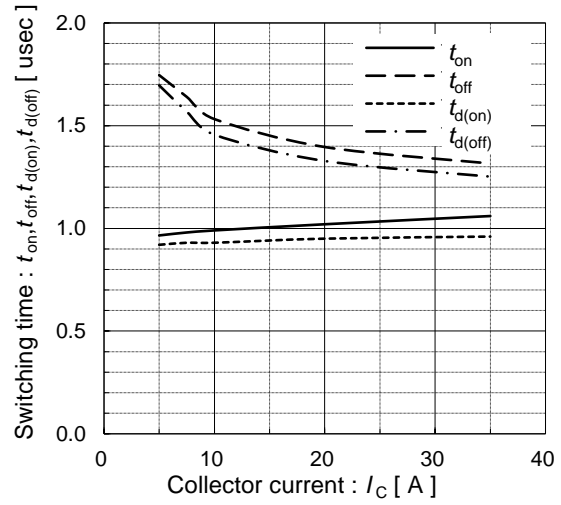
Switching time vs. Collector current (typ.)

$V_{DC}=600V, V_{CC}=15V, T_{vj}=25^{\circ}C$



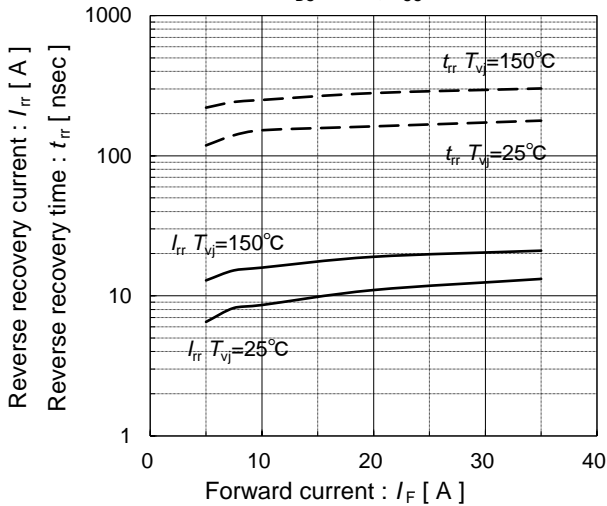
Switching time vs. Collector current (typ.)

$V_{DC}=600V, V_{CC}=15V, T_{vj}=150^{\circ}C$



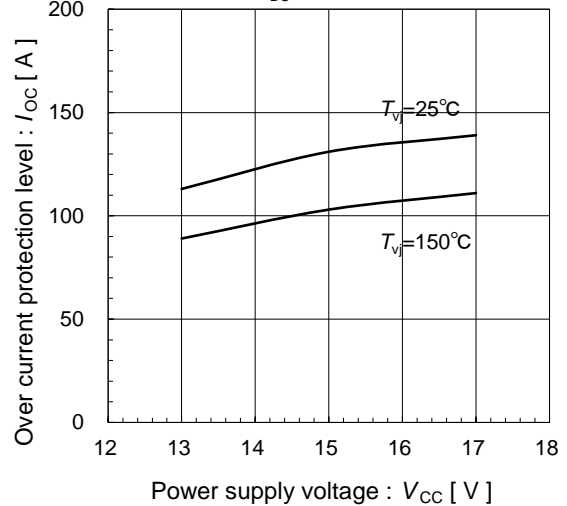
Reverse recovery characteristics (typ.)

$V_{DC}=600V, V_{CC}=15V$

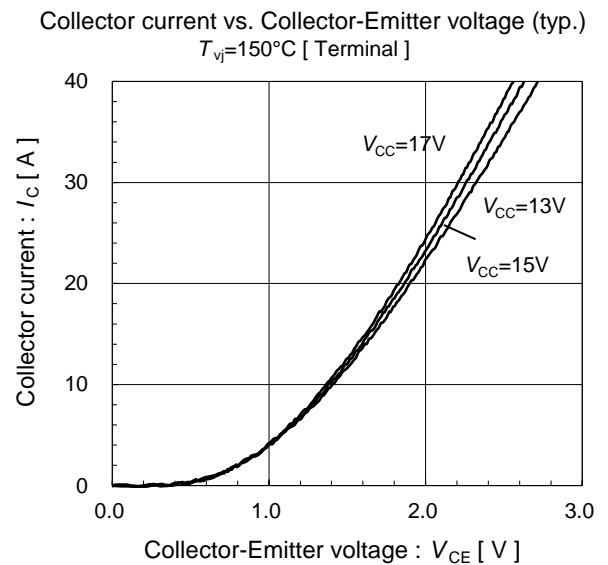
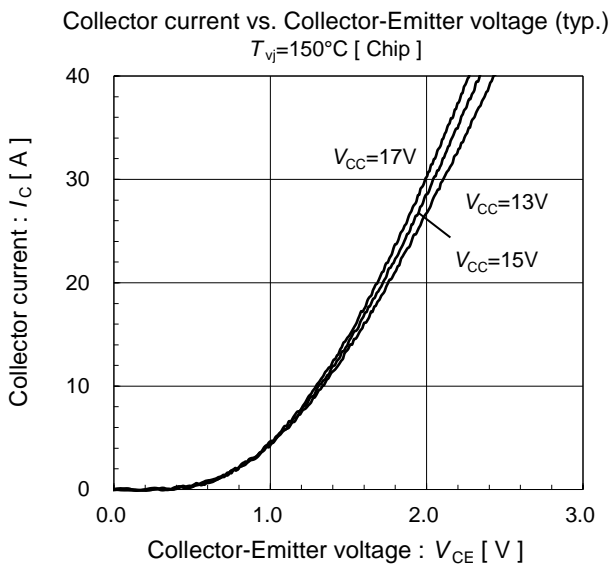
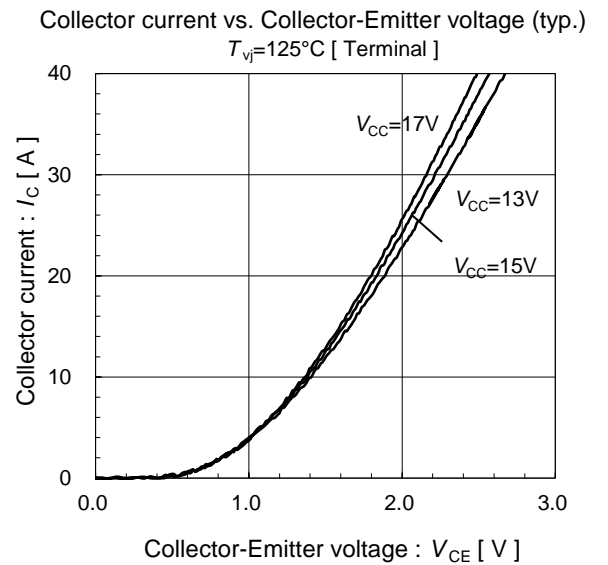
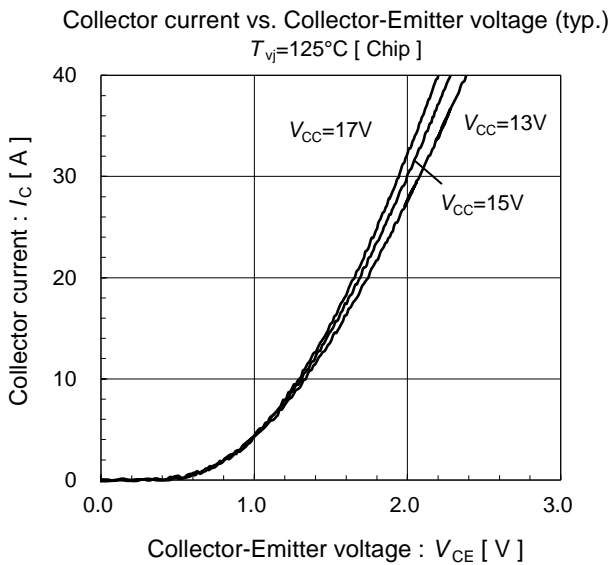
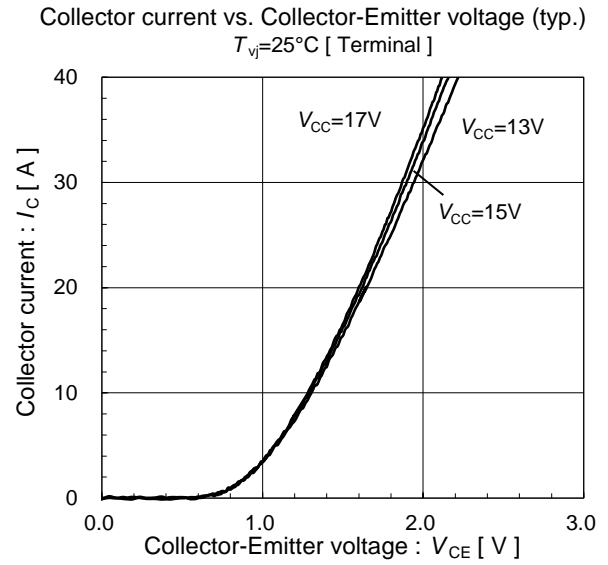
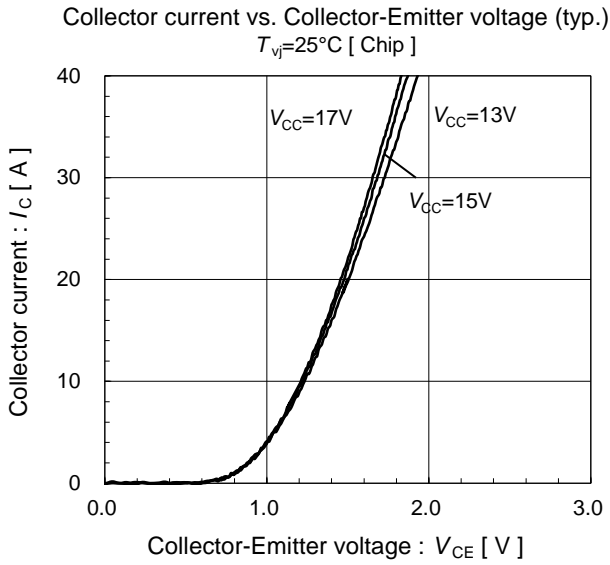


Over current protection vs. Power supply voltage (typ.)

$V_{DC}=600V$

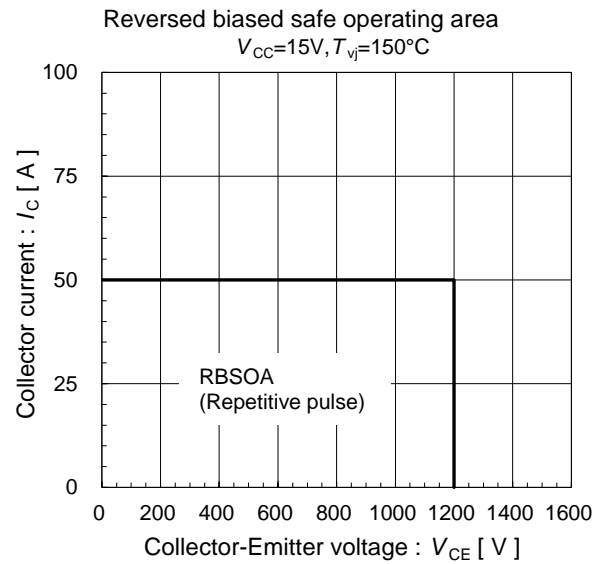
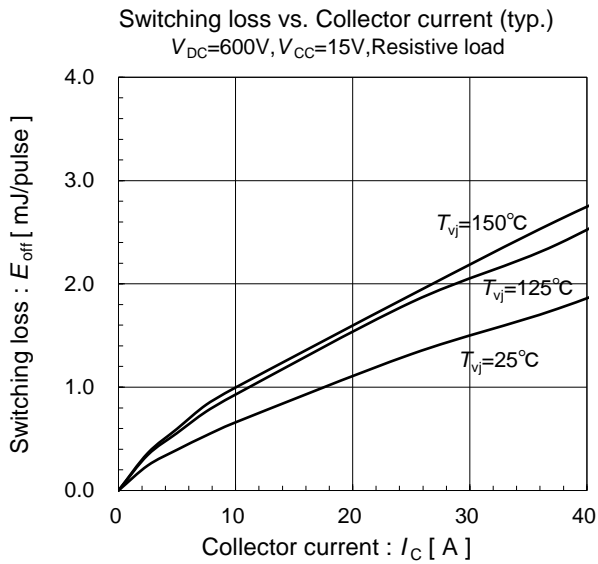
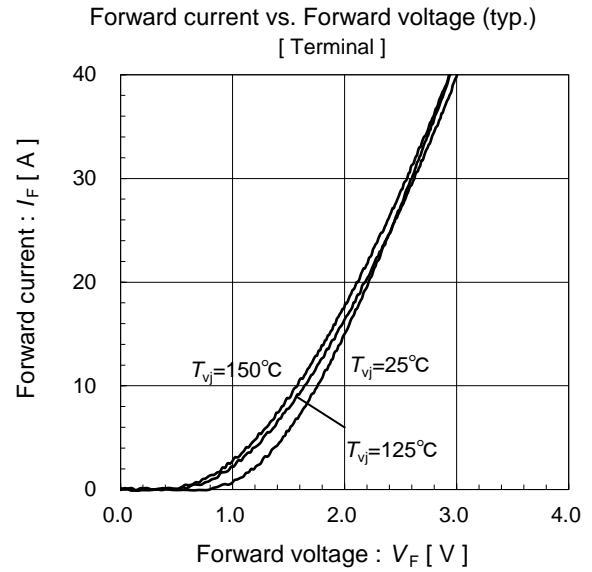
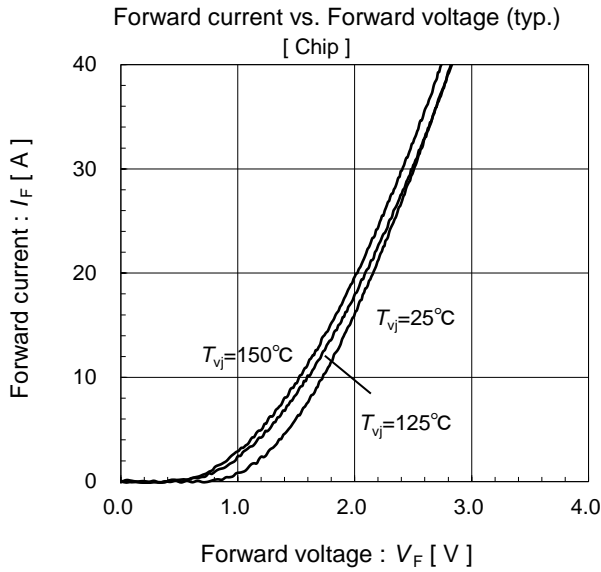


● Brake



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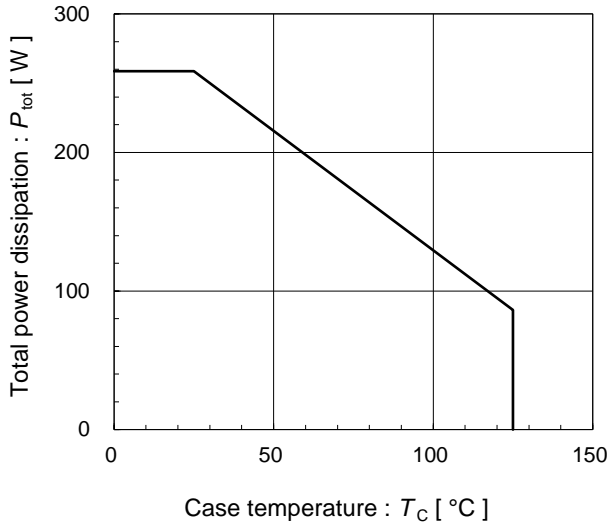
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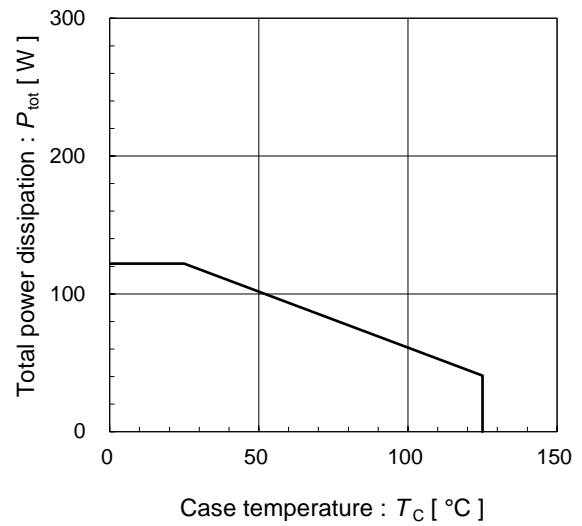
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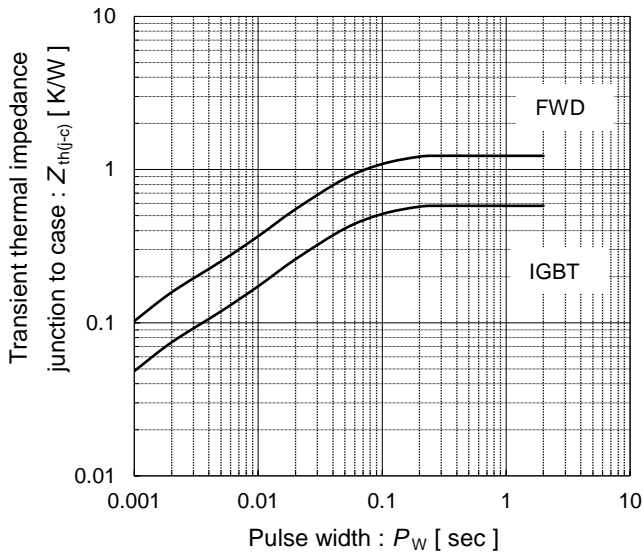
Power derating for IGBT (max.)
[per device]



Power derating for FWD (max.)
[per device]



Transient thermal resistance (max.)



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